

**Japanese Patent Application JPA 2020-131313
on Double Junction Pinned Photodiode type Solar Cell
filed on August 1, 2020 by Yoshiaki Hagiwara.**

Fig. 1 of JPA 2020-13131 on Cross Section

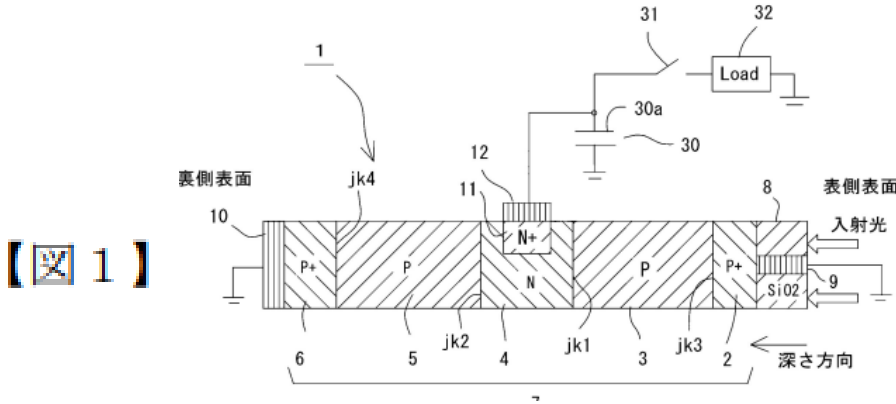


Fig. 2 of JPA 2020-13131 on Doping Profile D(x)

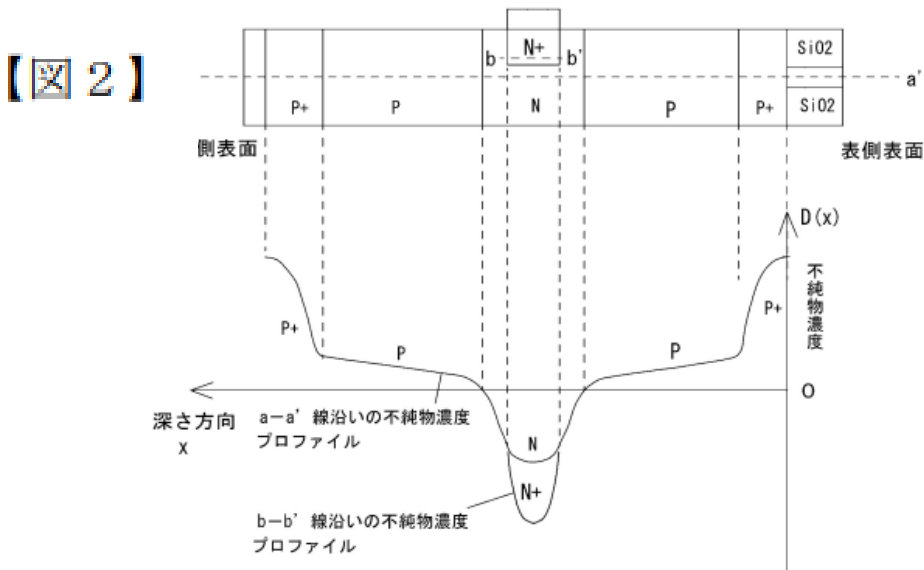


Fig. 3 of JPA 2020-13131 on the Ec and Ev Band Diagrams

